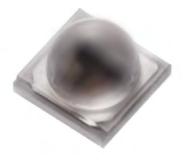


#### DATASHEET

## **High Power Infrared LED**

### **EAIST3535A4**



#### **Features**

- · Small package with high efficiency
- · Peak wavelength λp =850 nm
- Soldering methods: SMT
- Thermal resistance (junction to lead): 18K/W.
- · Pb free
- · Compliance with EU REACH
- · Compliance Halogen Free(Br < 900ppm, Cl < 900ppm, Br+Cl < 1500ppm)
- · The product itself will remain within RoHS compliant version.

#### **Description**

- EAIST3535A4 series is an infrared emitting diode in miniature SMD package which is molded in a water clear silicone with spherical top view lens.
- The device is spectrally matched with silicon photo diode, Photo-transistor.

### **Applications**

- · CCD Camera
- Infrared applied system

#### **Device Selection Guide**

LED Part No.	Chip Material	Lens Color
EAIST3535A4	GaAlAs	Water clear



## **Absolute Maximum Ratings (T<sub>A</sub>=25°C)**

Parameter	Symbol	Rating	Unit	
Continuous Forward Current	I <sub>F</sub>	1500	mA	
Peak Forward Current *1	I <sub>FP</sub>	5000	mA	
Reverse Voltage	$V_{R}$	5	V	
Operating Temperature	$T_{opr}$	-40~ +125	$^{\circ}$	
Storage Temperature	$T_{stg}$	-40 ~ +125	$^{\circ}$	
Junction temperature	T <sub>i</sub>	125	$^{\circ}$	
Thermal resistance	D	18	K /W	
(junction to lead frame)	$R_{th(j-L)}$	10	r\/VV	
Power Dissipation @I <sub>F</sub> =700mA	$P_d$	3	W	

#### Notes:

# Electro-Optical Characteristics (T<sub>A</sub>=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
			500			I <sub>F</sub> =350 mA
Total Radiated Power	Po		900		mW	I <sub>F</sub> =700 mA
			1300			I <sub>F</sub> =1 A
			200			I <sub>F</sub> =350 mA
Radiant Intensity	Ι <sub>Ε</sub>		400		mW/sr	I <sub>F</sub> =700 mA
			560		_	I <sub>F</sub> =1 A
Peak Wavelength	$\lambda_{P}$		850		nm	I <sub>F</sub> =350 mA
Spectral Bandwidth	Δλ		25		nm	I <sub>F</sub> =350 mA
			3.0			I <sub>F</sub> =350 mA
Forward Voltage	V <sub>F</sub> -		3.3		· V –	I <sub>F</sub> =700 mA
			3.5		V -	I <sub>F</sub> =1 A
			3.8			I <sub>F</sub> =5 A *3
Reverse Current	I <sub>R</sub>			10	μΑ	V <sub>R</sub> =5 V
View Angle	2θ <sub>1/2</sub>		90		deg	I <sub>F</sub> =20 mA

#### Notes:

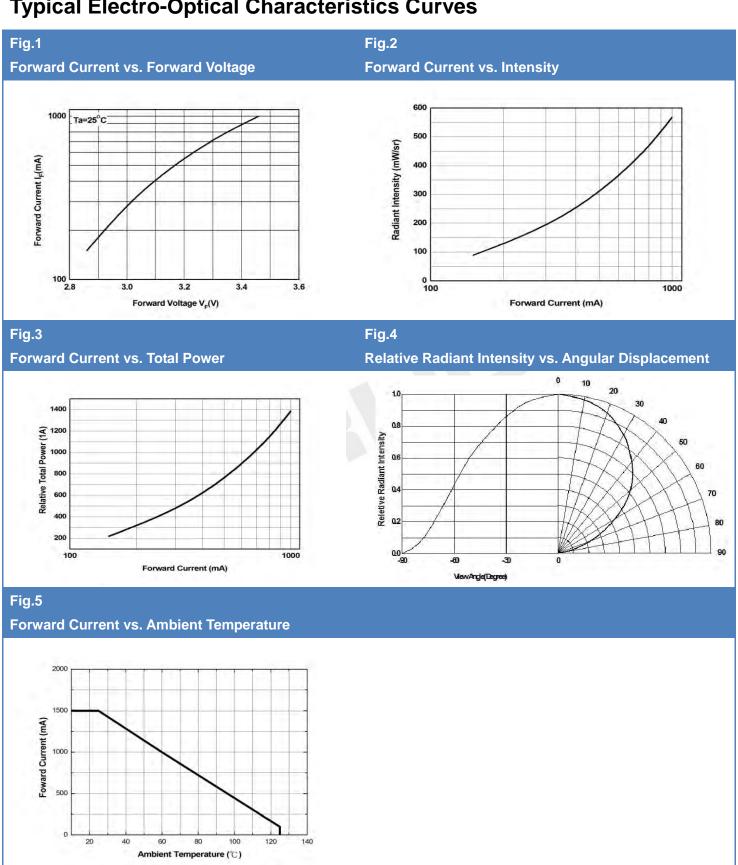
<sup>\*1.</sup> I<sub>FP</sub> Conditions--Pulse Width ≤ 100µs and Duty ≤ 1%

<sup>\*2.</sup> Note: We suggest that customer should add the heat sink with EAIST3535A4 to exclude the heat.

<sup>\*3.</sup>  $I_{FP}$  Conditions--Pulse Width $\leq$ 100 $\mu$ s and Duty $\leq$ 1%



## **Typical Electro-Optical Characteristics Curves**





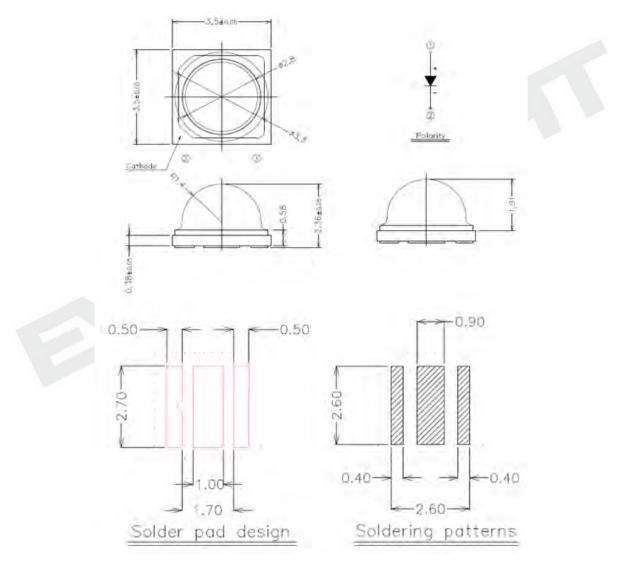
#### **Bin Code List**

Radiated Power Condition: I<sub>F</sub>=1000mA Unit: mW

Bin Number	G	Н	1
Min	800	1000	1260
Max	1260	1600	2000

Including test tolerance ±10%

## **Package Dimension**

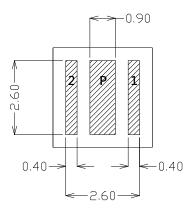


- 1. Dimensions are in millimeters.
- 2. Tolerances unless mentioned are ± 0.1mm.
- 3. Do not handle the device by the lens. Incorrect force applied to the lens may lead to the failure of devices.



## **Pad Configuration**

Pad	1	2	Р
Function	Anode	Cathode	Thermal Pad



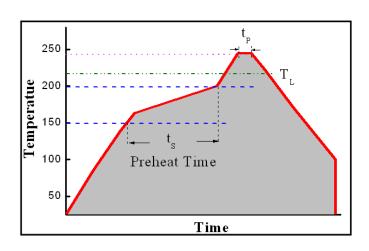
Recommend Soldering patterns

## **Reflow Soldering Characteristics**

### **For Reflow Process**

- 1. C19 series are suitable for SMT processes.
- 2. Curing of glue in oven must be according to standard operation flow processes.

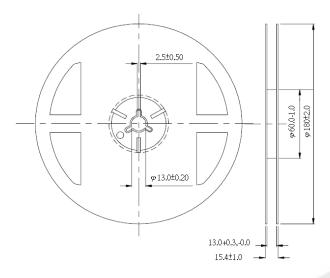
Profile Feature	Lead Free	Unit
	Assembly	
Ramp-Up Rate	2~3	°C/S
Preheat Temperature	150~200	${}^{\circ}\! {\mathbb C}$
Preheat Time(t <sub>S</sub> )	60~120	S
Liquid Temperature(T <sub>L</sub> )	217	°C
Time maintained above	60~90	S
TL		
Peak Temperature(T <sub>P</sub> )	240+-5	°C
Peak Time (t <sub>P</sub> )	Max 20	S
Ramp-Down Rate	3~5	°C/S



- 3. Reflow soldering should not be done more than twice.
- 4. In soldering process, stress on the LEDs during heating should be avoided.
- 5. After soldering, do not bend the circuit board.



# **Package Dimensions**

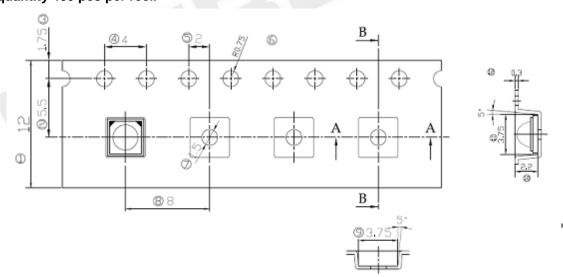


#### Note:

- 1. Dimensions are in millimeters
- 2. The tolerances unless mentioned is ±0.1mm

## **Carrier Tape Dimensions:**

Loaded quantity 400 pcs per reel.

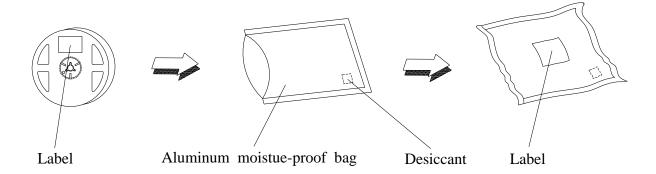


#### Note:

- 1. Dimensions are in millimeters
- 2. The tolerances unless mentioned is ±0.1mm

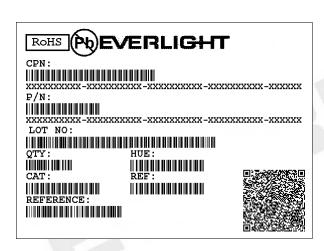


#### Mois



## **Moisture Resistant Packing Materials**

### **Label Form Specification**



- CPN: Customer's Product Number
- P/N: Product Number
- · QTY: Packing Quantity
- · CAT: Luminous Intensity Rank
- · HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- · LOT No: Lot Number
- X: Month
- · Reference: Identify Label Number



#### **DISCLAIMER**

- 1. EVERLIGHT reserves the right(s) on the adjustment of product material mix for the specification.
- 2. The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
- 3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 4. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from the use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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